

# RRS090P03HZG

Pch -30V -9A Power MOSFET

# Datasheet

| V <sub>DSS</sub>           | -30V   |
|----------------------------|--------|
| R <sub>DS(on)</sub> (Max.) | 15.4mΩ |
| Ι <sub>D</sub>             | ±9A    |
| P <sub>D</sub>             | 2.0W   |

## Features

- 1) Low on-resistance
- 2) Small Surface Mount Package (SOP8)
- 3) Pb-free lead plating ; RoHS compliant
- 4) Halogen Free

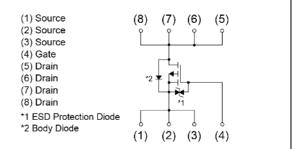
Application

Switching

- 5) Sn100% plating
- 6) AEC-Q101 Qualified

# • Outline SOP8

#### ●Inner circuit



### Packaging specifications

|      | Packing         | Embossed<br>Tape |
|------|-----------------|------------------|
|      | Reel size (mm)  | 330              |
| Туре | Tape width (mm) | 12               |
|      | Quantity (pcs)  | 2500             |
|      | Taping code     | ТВ               |
|      | Marking         | RRS090P03        |

### • Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

| Parameter                                        | Symbol             | Value       | Unit |
|--------------------------------------------------|--------------------|-------------|------|
| Drain - Source voltage                           | V <sub>DSS</sub>   | -30         | V    |
| Continuous drain current                         | I <sub>D</sub>     | ±9          | А    |
| Pulsed drain current                             | I <sub>DP</sub> *1 | ±36         | А    |
| Gate - Source voltage                            | V <sub>GSS</sub>   | ±20         | V    |
| Device dissisction                               | P <sub>D</sub> *2  | 2.0         | W    |
| Power dissipation                                | P <sub>D</sub> *3  | 1.4         | W    |
| Junction temperature                             | Tj                 | 150         | °C   |
| Operating junction and storage temperature range | T <sub>stg</sub>   | -55 to +150 | °C   |

### •Thermal resistance

| Deremeter                              | Sumbol          |      | Values |      | Unit |
|----------------------------------------|-----------------|------|--------|------|------|
| Parameter                              | Symbol          | Min. | Тур.   | Max. | Unit |
| Thermal registeres innotion embient    | $R_{thJA}^{*2}$ | -    | -      | 62.5 | °C/W |
| Thermal resistance, junction - ambient | $R_{thJA}^{*3}$ | -    | -      | 89.2 | °C/W |

# •Electrical characteristics (T<sub>a</sub> = 25°C)

| Deremeter                                      | Symbol Conditions -                     |                                                 | Values |       |      | Unit  |  |
|------------------------------------------------|-----------------------------------------|-------------------------------------------------|--------|-------|------|-------|--|
| Parameter                                      |                                         |                                                 | Min.   | Тур.  | Max. | Unit  |  |
| Drain - Source breakdown<br>voltage            | V <sub>(BR)DSS</sub>                    | V <sub>GS</sub> = 0V, I <sub>D</sub> = -1mA     | -30    | -     | -    | V     |  |
| Breakdown voltage<br>temperature coefficient   | $\frac{\Delta V_{(BR)DSS}}{\Delta T_j}$ | I <sub>D</sub> = -1mA<br>referenced to 25°C     | -      | -24.1 | -    | mV/°C |  |
| Zero gate voltage<br>drain current             | I <sub>DSS</sub>                        | V <sub>DS</sub> = -30V, V <sub>GS</sub> = 0V    | -      | -     | -1   | μA    |  |
| Gate - Source leakage current                  | I <sub>GSS</sub>                        | $V_{GS}$ = ±20V, $V_{DS}$ = 0V                  | -      | -     | ±10  | μA    |  |
| Gate threshold voltage                         | $V_{GS(th)}$                            | V <sub>DS</sub> = -10V, I <sub>D</sub> = -1mA   | -1.0   | -     | -2.5 | V     |  |
| Gate threshold voltage temperature coefficient | $\frac{\Delta V_{GS(th)}}{\Delta T_j}$  | I <sub>D</sub> = -1mA<br>referenced to 25°C     | -      | 3.3   | -    | mV/°C |  |
|                                                |                                         | V <sub>GS</sub> = -10V, I <sub>D</sub> = -9.0A  | -      | 11.0  | 15.4 |       |  |
| Static drain - source<br>on - state resistance | R <sub>DS(on)</sub> *4                  | V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -4.5A | -      | 15.0  | 21.0 | mΩ    |  |
|                                                |                                         | V <sub>GS</sub> = -4.0V, I <sub>D</sub> = -4.5A | -      | 17.0  | 24.0 | 1     |  |
| Gate resistance                                | $R_{G}$                                 | f = 1MHz, open drain                            | -      | 2.7   | -    | Ω     |  |
| Forward Transfer<br>Admittance                 | Y <sub>fs</sub>   <sup>*4</sup>         | V <sub>DS</sub> = -10V, I <sub>D</sub> = -9A    | 10     | -     | -    | S     |  |

\*1 Pw  $\leq$ 10µs, Duty cycle  $\leq$ 1%

- \*2 Mounted on a ceramic board (30×30×0.8mm)
- \*3 Mounted on a Cu board (40×40×0.8mm)
- \*4 Pulsed



# • Electrical characteristics ( $T_a = 25^{\circ}C$ )

| Deremeter                    | Sumpleal              | Conditions                          | Values |      |      | Unit |  |
|------------------------------|-----------------------|-------------------------------------|--------|------|------|------|--|
| Parameter                    | Symbol Conditions –   |                                     | Min.   | Тур. | Max. | Unit |  |
| Input capacitance            | C <sub>iss</sub>      | V <sub>GS</sub> = 0V                | -      | 3000 | -    |      |  |
| Output capacitance           | C <sub>oss</sub>      | V <sub>DS</sub> = -10V              | -      | 360  | -    | pF   |  |
| Reverse transfer capacitance | C <sub>rss</sub>      | f = 1MHz                            | -      | 360  | -    |      |  |
| Turn - on delay time         | t <sub>d(on)</sub> *4 | $V_{DD} \simeq -15V, V_{GS} = -10V$ | -      | 20   | -    |      |  |
| Rise time                    | t <sub>r</sub> *4     | I <sub>D</sub> = -4.5A              | -      | 30   | -    | 20   |  |
| Turn - off delay time        | $t_{d(off)}^{*4}$     | $R_L \simeq 3.3\Omega$              | -      | 135  | -    | ns   |  |
| Fall time                    | t <sub>f</sub> *4     | R <sub>G</sub> = 10Ω                | -      | 80   | -    |      |  |

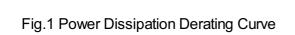
# • Gate charge characteristics ( $T_a = 25^{\circ}C$ )

| Parameter            | Symbol                    | Conditions                                     | Values |      |      | Unit |
|----------------------|---------------------------|------------------------------------------------|--------|------|------|------|
| Farameter            | Symbol                    | Conditions                                     | Min.   | Тур. | Max. | Unit |
| Total gate charge    | Q <sub>g</sub> *4         | V <sub>DD</sub> ≃ -15V,                        | -      | 30   | -    |      |
| Gate - Source charge | Q <sub>gs</sub> *4        | I <sub>D</sub> = -9A,<br>V <sub>GS</sub> = -5V | -      | 7    | -    | nC   |
| Gate - Drain charge  | ${\sf Q}_{\sf gd}{}^{*4}$ | V <sub>GS</sub> = -5V                          | -      | 11   | -    |      |

# •Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

| Parameter                  | Symbol         | Conditions                                 | Values |      |      | Unit |  |
|----------------------------|----------------|--------------------------------------------|--------|------|------|------|--|
|                            | Symbol         | Conditions                                 | Min.   | Тур. | Max. | Unit |  |
| Continuous forward current | ۱ <sub>s</sub> | T - 25°0                                   | -      | -    | -1.6 | А    |  |
| Pulse forward current      | $I_{SP}^{*1}$  | T <sub>a</sub> = 25°C                      | -      | -    | -36  | А    |  |
| Forward voltage            | $V_{SD}^{*4}$  | V <sub>GS</sub> = 0V, I <sub>S</sub> = -9A | -      | -    | -1.2 | V    |  |





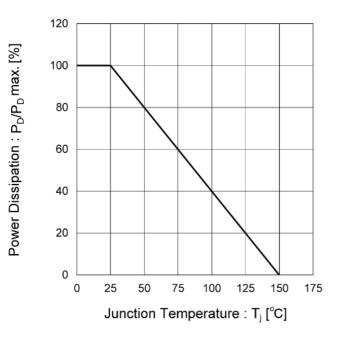


Fig.2 Maximum Safe Operating Area

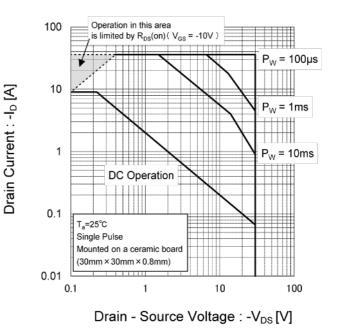
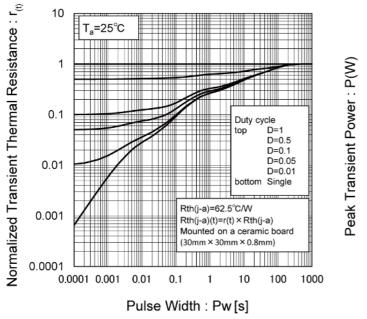
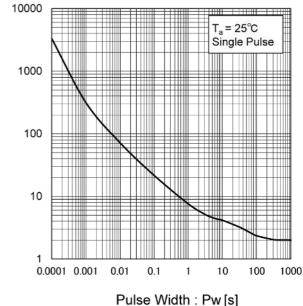


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

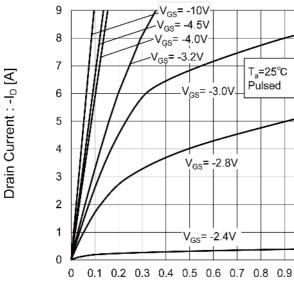
Fig.4 Single Pulse Maximum Power dissipation







#### Electrical characteristic curves



#### Fig.5 Typical Output Characteristics(I)

V<sub>GS</sub>= -10V

V<sub>GS</sub>= -4.5V

√<sub>GS</sub>= -4.0V

V<sub>GS</sub>= -3.0V

V<sub>GS</sub>= -2.8V

V<sub>GS</sub>= -2.4V

Drain - Source Voltage : -V<sub>DS</sub> [V]

T<sub>a</sub>=25°C

Pulsed

Drain Current : -I<sub>D</sub> [A]

1

-V<sub>GŞ</sub>= -3.2V

# Fig.6 Typical Output Characteristics(II)

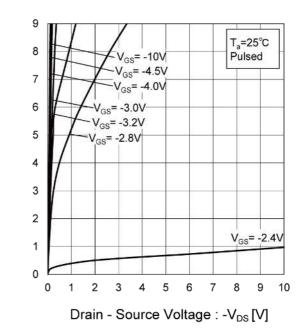
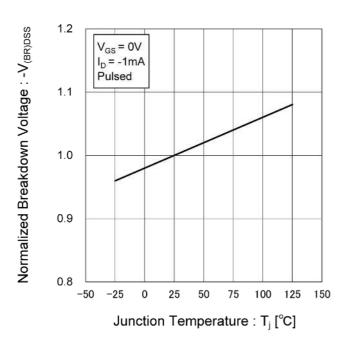
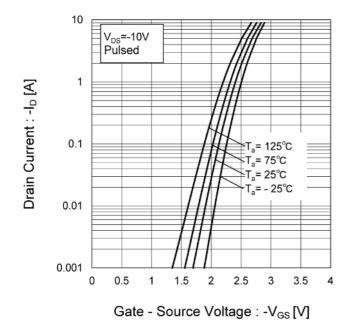


Fig.7 Breakdown Voltage vs. **Junction Temperature** 



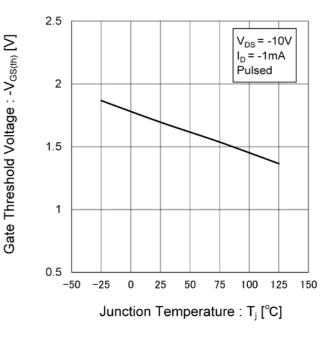


#### • Electrical characteristic curves

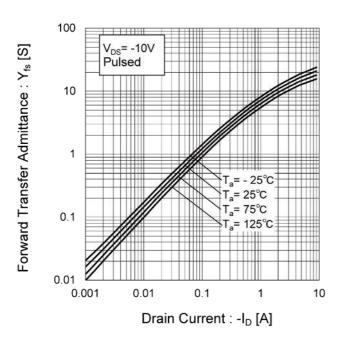


# Fig.8 Typical Transfer Characteristics

#### Fig.9 Gate Threshold Voltage vs. Junction Temperature



# Fig.10 Forward Transfer Admittance vs. Drain Current







## • Electrical characteristic curves

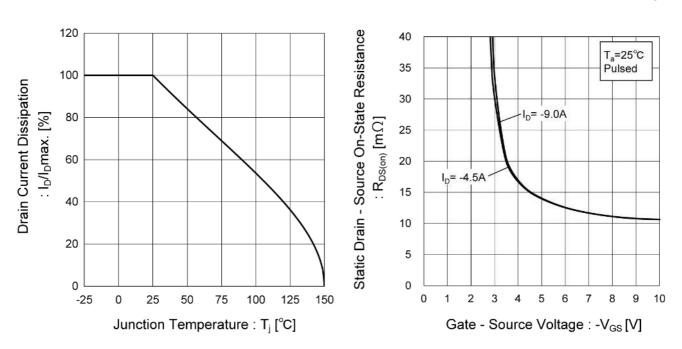


Fig.11 Drain Current Derating Curve

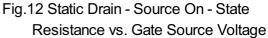
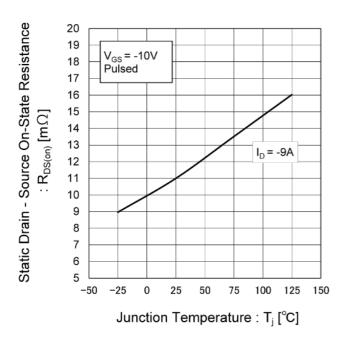
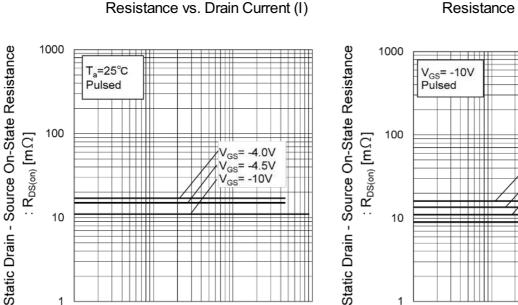


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature





0.01



1

10

Fig.14 Static Drain - Source On - State Resistance vs. Drain Current (I) Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

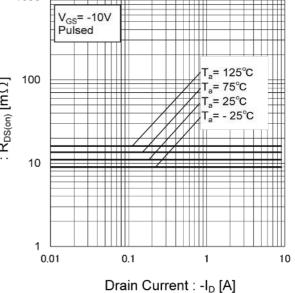
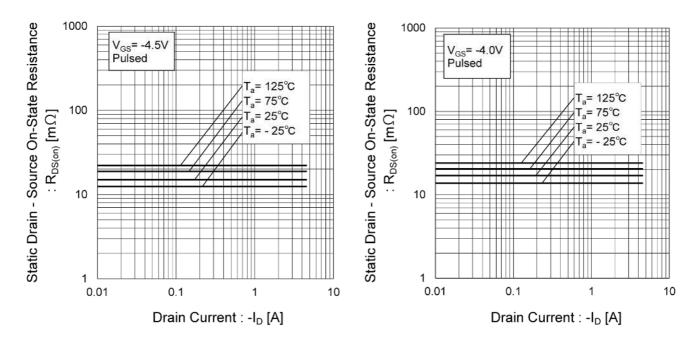


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)

Drain Current : -I<sub>D</sub> [A]

0.1

Fig.17 Static Drain - Source On - State Resistance vs. Drain Current (IV)





## • Electrical characteristic curves

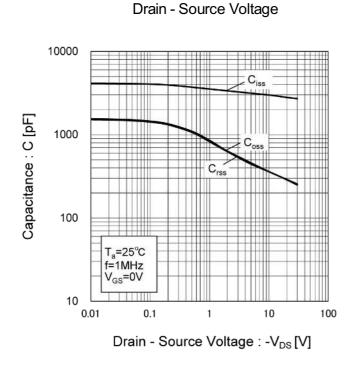


Fig.18 Typical Capacitance vs.

#### Fig.19 Switching Characteristics

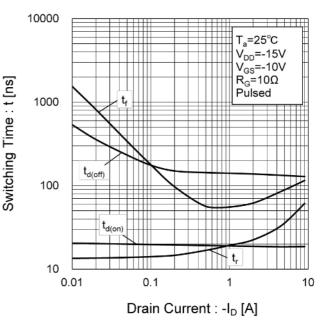


Fig.20 Dynamic Input Characteristics

Gate - Source Voltage : -V<sub>GS</sub> [V]

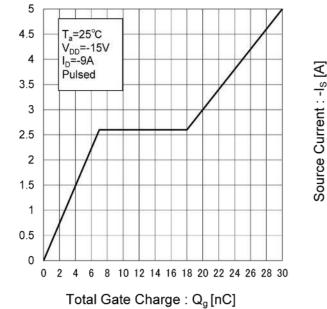
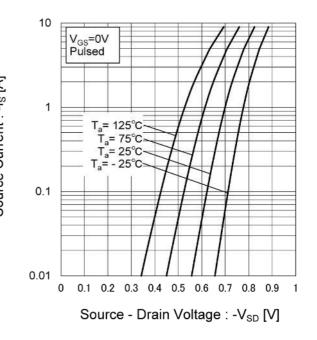


Fig.21 Source Current vs. Source Drain Voltage





#### Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

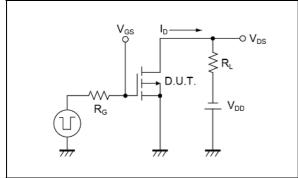


Fig.2-1 Gate Charge Measurement Circuit

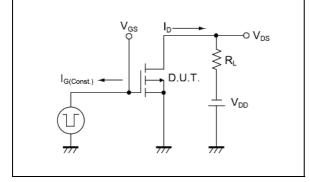
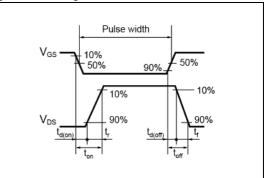
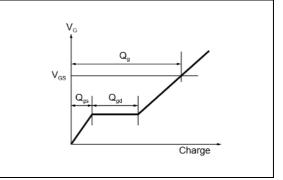


Fig.1-2 Switching Waveforms



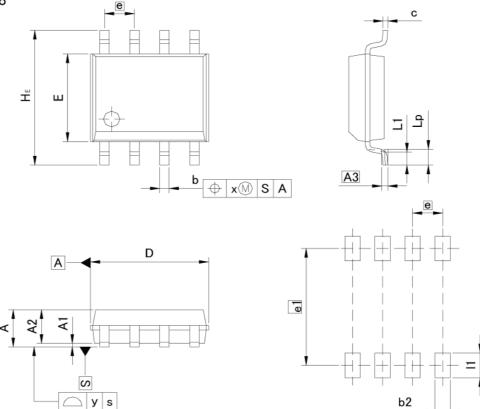






#### Dimensions

SOP8



Pattern of terminal position areas [Not a pattern of soldering pads]

|    | MILIM      | ETERS | INCHES |       |
|----|------------|-------|--------|-------|
|    | MIN        | MAX   | MIN    | MAX   |
| A  | <u>-</u> 2 | 1.75  | -      | 0.069 |
| A1 | 0.         | 15    | 0.0    | 06    |
| A2 | 1.40       | 1.60  | 0.055  | 0.063 |
| A3 | 0.         | 25    | 0.0    | 10    |
| b  | 0.30       | 0.50  | 0.012  | 0.020 |
| с  | 0.10       | 0.30  | 0.004  | 0.012 |
| D  | 4.80       | 5.20  | 0.189  | 0.205 |
| E  | 3.75       | 4.05  | 0.148  | 0.159 |
| е  | 1.         | 27    | 0.0    | 50    |
| HE | 5.70       | 6.30  | 0.224  | 0.248 |
| L1 | 0.40       | 0.60  | 0.016  | 0.024 |
| Lp | 0.65       | 0.85  | 0.026  | 0.033 |
| x  | 0.15       |       | 0.006  |       |
| У  | 0.         | 10    | 0.0    | 04    |

| DIM | MILIM         | ETERS | INC          | HES   |
|-----|---------------|-------|--------------|-------|
|     | MIN           | MAX   | MIN          | MAX   |
| b2  |               | 0.65  | <del></del>  | 0.026 |
| e1  | 5.15          |       | 0.1          | 203   |
| 11  | <del></del> 2 | 1.15  | <b>27</b> (2 | 0.045 |

Dimension in mm/inches



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| (Note1) Medical Equipment Classification of the Specific Applications |
|-----------------------------------------------------------------------|
|-----------------------------------------------------------------------|

| JAPAN   | USA    | EU         | CHINA   |
|---------|--------|------------|---------|
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| CLASSIV | CLASSI | CLASSⅢ     | CLASSII |

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- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
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For details, please refer to ROHM Mounting specification

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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